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internal circuits.

Data Sheet

COMPLEMENTARY OUTPUT HALL EFFECT LATCH

AH277A

General Description

Features

- On-Chip Hall Sensor
- 3.5V to 16V Supply Voltage
- 400mA (avg) Output Sink Current
- Reversed Supply Voltage Protection
- -20°C to 85°C Operating Temperature
- Low Profile TO-94 (SIP-4L) Package
- ESD Rating: 300V (Machine Model)

Applications

- Dual-Coil Brushless DC Motor
- Dual-Coil Brushless DC Fan
- Revolution Counting
- Speed Measurement

Placing the device in a variable magnetic field, if the magnetic flux density is larger than threshold B_{OP} the pin DO will be turned low (on) and pin DOB will be turned high (off). This output state is held until the magnetic flux density reverses and falls below B_{RP} , then causes DO to be turned high (off) and DOB turned low (on).

The AH277A is an integrated Hall sensor with output

driver designed for electronic commutation of brush-

less DC motor applications. The device includes an on-

chip Hall sensor for magnetic sensing, an amplifier

that amplifies the Hall voltage, a Schmitt trigger to

provide switching hysteresis for noise rejection, a tem-

perature compensation circuit to compensate the tem-

perature drift of Hall sensitivity and two complementary open-collector drivers for sinking large load current. It also includes an internal band-gap

regulator which is used to provide bias voltage for

AH277A is available in TO-94 (SIP-4L) package.

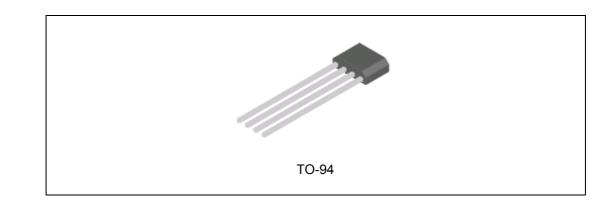


Figure 1. Package Type of AH277A



COMPLEMENTARY OUTPUT HALL EFFECT LATCH

AH277A

Pin Configuration

Z4 Package (TO-94)

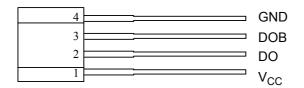


Figure 2. Pin Configuration of AH277A (Front View)

Pin Description

Pin Number	Pin Name	Function
1	V _{CC}	Supply voltage
2	DO	Output 1
3	DOB	Output 2
4	GND	Ground



COMPLEMENTARY OUTPUT HALL EFFECT LATCH

AH277A

Functional Block Diagram

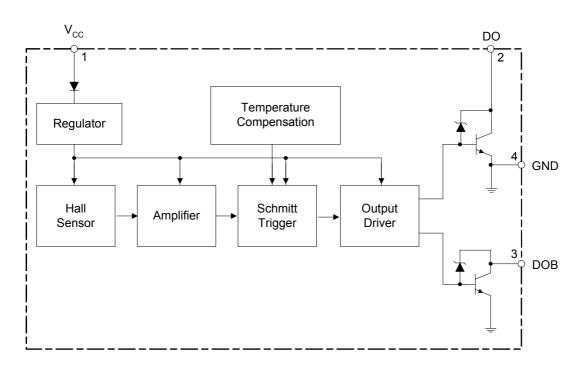
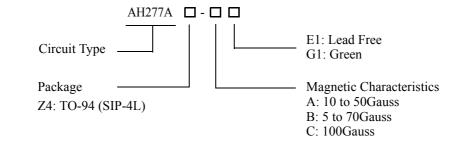


Figure 3. Functional Block Diagram of AH277A

Ordering Information



Package Temperature Range	Part N	umber	Marki	Packing		
	Lead Free	Green	Lead Free	Green	Туре	
		AH277AZ4-AE1	AH277AZ4-AG1	AH277A	AH277A-G1	Bulk
TO-94	-20 to 85°C	AH277AZ4-BE1	AH277AZ4-BG1	AH277A	AH277A-G1	Bulk
	AH277AZ4-CE1	AH277AZ4-CG1	AH277A	AH277A-G1	Bulk	

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green package.

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COMPLEMENTARY OUTPUT HALL EFFECT LATCH

AH277A

Absolute Maximum Ratings (Note 1)

 $(T_A = 25^{\circ}C)$

Parameter	Symbol	Value	Unit	
Supply Voltage		V _{CC}	20	V
Reverse Protection Voltage		V _{RCC}	-20	V
Magnetic Flux Density		В	Unlimited	Gauss
	Continuous		400	mA
Output Current	Hold	I _O	600	mA
	Peak (start up)		800	mA
Power Dissipation		P _D	550	mW
Thermal Resistance	Die to atmosphere	θJA	227	°C/W
I nermai Kesistance	Die to package case	θJC	49	°C/W
Storage Temperature		T _{STG}	-50 to 150	°C
ESD (Machine Model)			300	V
ESD (Human Body Model)			2000	V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. "Absolute Maximum Ratings" for extended period may affect device reliability.

Recommended Operating Conditions

 $(T_A = 25^{\circ}C)$

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V _{CC}	3.5	16	V
Ambient Temperature	T _A	-20	85	°C



COMPLEMENTARY OUTPUT HALL EFFECT LATCH

AH277A

Electrical Characteristics

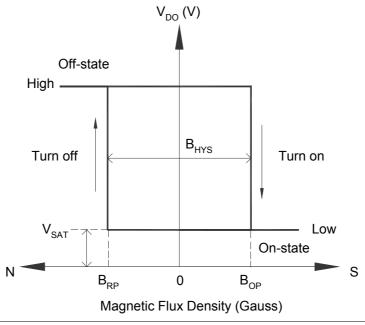
($T_A=25^{\circ}C$, $V_{CC}=14V$, unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Output Saturation Voltage	V _{SAT}	V _{CC} =3.5V, I _O =100mA		0.4		V
	SAI	I _O =400mA	0.35	0.6	V	
Output Leakage Current	I _{OL}	V _{CE} =16V		0.1	10	μΑ
Supply Current	I _{CC}	V _{CC} =16V, Output Open		12	16	mA
Output Rise Time	tr	R _L =820Ω, C _L =20pF		3.0	10	μs
Output Fall Time	tf	R _L =820Ω, C _L =20pF		0.3	1.5	μs
Switch Time Differential	Δt	R _L =820Ω, C _L =20pF		3.0	10	μs
Output Zener Breakdown Voltage	VZ			55		V

Magnetic Characteristics

 $(T_A = 25^{\circ}C)$

Parameter	Symbol	Grade	Min	Тур	Max	Unit
Operating Point	B _{OP}	А	10	30	50	Gauss
		В	5		70	Gauss
		С			100	Gauss
Releasing Point		А	-50	-30	-10	Gauss
	B _{RP}	В	-70		-5	Gauss
		С	-100			Gauss
Hysteresis	B _{HYS}			60		Gauss



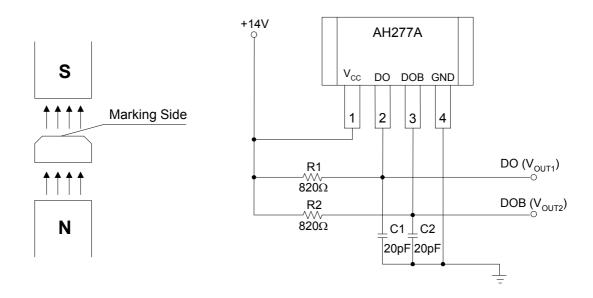
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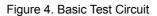


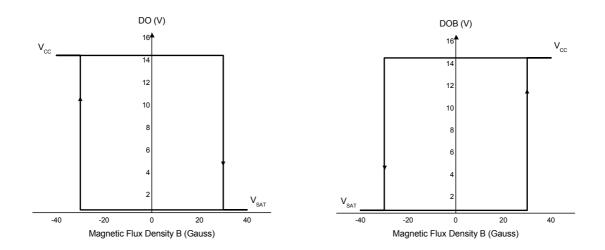
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Magnetic Characteristics (Continued)











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AH277A

Typical Performance Characteristics

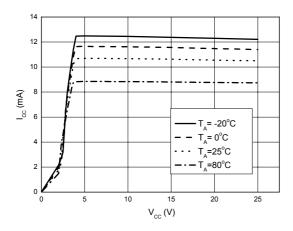




Figure 8. $B_{OP}/B_{RP}/B_{HYS}$ vs. V_{CC}

15

 V_{cc} (V)

20

25

10

60 50

40

30

20 10

0

-10

-20 -30 ∟ 0 B

- B_{RP}

В

5

 $B_{OP},\,B_{RP},\,B_{H\gamma}\,(Gauss)$

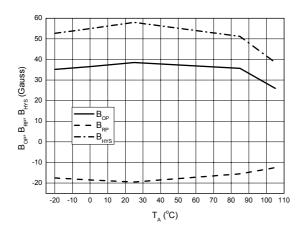
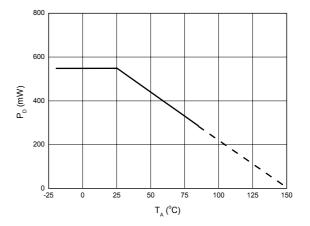


Figure 9. $B_{OP}/B_{RP}/B_{HYS}\,vs.$ Ambient Temperature





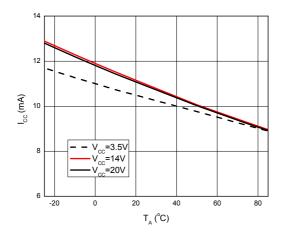
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AH277A

Typical Performance Characteristics (Continued)



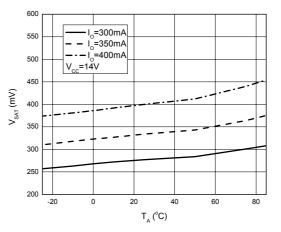


Figure 11. Supply Current vs. Ambient Temperature

Figure 12. Saturation Voltage vs. Ambient Temperature

Typical Applications

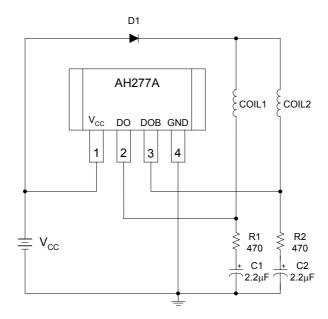


Figure 13. Typical Application Circuit with D1(Note 2)

Note 2: AH277A has Reversed Supply Voltage Protection. For DC fan application, sometimes need to test power reverse connection condition. The internal diode only protects chip-side but not for coil-side. It is recommended to add one external diode D1 in application to block the reverse current from coil-side as shown in Figure 13.

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COMPLEMENTARY OUTPUT HALL EFFECT LATCH

AH277A

Unit: mm(inch)

Mechanical Dimensions

TO-94 45° TYP 3.780(0.149) 0.500(0.020) 0.700(0.028) 4.080(0.161) 1.520(0.059) 1.720(0.067) Τ 4.980(0.196) 0.360(0.014) 5.280(0.208) 0.510(0.020) 0.700(0.028) 0.900(0.035) 1.850(0.073) A 1.250(0.050) ł 3.450(0.136) 0.380(0.015) 3.750(0.148) Package Sensor Location 0.550(0.022) (For Hall IC) T 0.360(0.014) 0.500(0.020) 14.000(0.550) 15.300(0.602) 1.270(0.050) TYP 3.710(0.146)

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3.910(0.154)



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